



80V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BVDSS	R _{DS(ON)} Max	I _D Max T _C = +25°C
001/	6.9mΩ @ V _{GS} = 10V	70A
80V	10.4mΩ @ V _{GS} = 4.5V	57A

Features and Benefits

- Rated to +175°C Ideal for High Ambient Temperature Environments
- Low Rds(ON) Ensures On-State Losses are Minimized
- Excellent Q_{qd} x R_{DS(ON)} Product (FOM)
- Advanced Technology for DC-DC Converts
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- Occupies Just 33% of the Board Area Occupied by SO-8 Enabling Smaller End Product
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH8008LFGQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

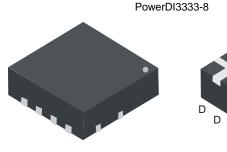
Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

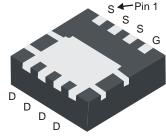
- Backlighting
- Power Management Functions
- DC-DC Converters

Mechanical Data

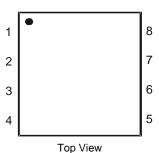
- Case: PowerDI[®]3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminal Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208(§3)
- Weight: 0.072 grams (Approximate)





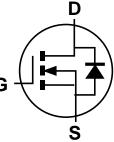


Bottom View



Pin-Out





Equivalent Circuit

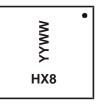
Ordering Information (Note 4)

Part Number	Case	Packaging
DMTH8008LFGQ-7	PowerDI3333-8	2,000/Tape & Reel
DMTH8008LFGQ-13	PowerDI3333-8	3,000/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



HX8 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 20 = 2020) WW = Week Code (01 to 53)



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	VDSS	80	V	
Gate-Source Voltage		V_{GSS}	±20	V
Continuous Drain Current (Note 7) V _{GS} = 10V	T _C = +25°C T _C = +100°C	lD	70 49	А
Continuous Drain Current (Note 6) $V_{GS} = 10V$ $T_A = +25^{\circ}C$ $T_A = +100^{\circ}C$		lo	17 12	А
Maximum Continuous Body Diode Forward Current (Note 6)	Is	45	Α	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	280	А	
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle =	I _{SM}	280	А	
Avalanche Current, L = 1mH (Note 8)	las	18	А	
Avalanche Energy, L = 1mH (Note 8)	Eas	162	mJ	

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	P _D	1.2	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{\theta JA}$	124	°C/W
Total Power Dissipation (Note 6)	T _A = +25°C	PD	2.8	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{\theta JA}$	53	°C/W
Total Power Dissipation (Note 7)	T _C = +25°C	Pp	50	W
Thermal Resistance, Junction to Case (Note 7)	R _θ JC	3	°C/W	
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +175	°C	

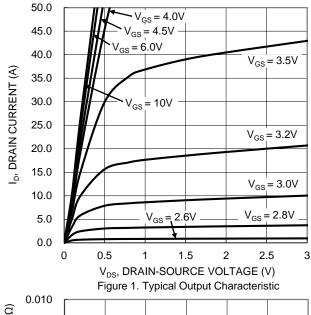
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

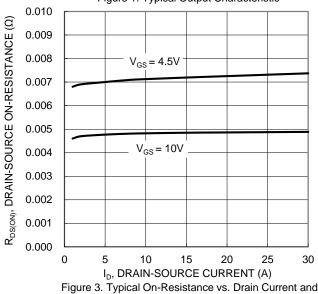
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BVDSS	80	_	_	V	$V_{GS} = 0V$, $I_{D} = 1mA$	
Zero Gate Voltage Drain Current	IDSS	-	_	1	μΑ	V _{DS} = 64V, V _{GS} = 0V	
Gate-Source Leakage	I _{GSS}	-	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	Vgs(TH)	1.2		2.5	V	V _{DS} = V _{GS} , I _D = 1mA	
Static Drain-Source On-Resistance	D	-	5.3	6.9	mΩ	Vgs = 10V, ID = 20A	
Static Drain-Source On-Resistance	RDS(ON)		7.9	10.4		V _G S = 4.5V, I _D = 10A	
Diode Forward Voltage	V _{SD}	_	0.8	1.2	V	V _{GS} = 0V, I _S = 20A	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	Ciss	-	2254	_		V _{DS} = 40V, V _{GS} = 0V, f = 1MHz	
Output Capacitance	Coss		745	_	pF		
Reverse Transfer Capacitance	Crss		31	_			
Gate Resistance	R_g	-	1.98	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (VGS = 4.5V)	Qg		18.3	_			
Total Gate Charge (V _{GS} = 10V)	Q_g	_	37.7	_			
Gate-Source Charge	Q_{gs}	-	5.3	_	nC	$V_{DS} = 40V, I_{D} = 14A$	
Gate-Drain Charge	Q_{gd}	-	7.8	_			
Turn-On Delay Time	t _{D(ON)}	_	6.9	_		$V_{DD} = 40V, V_{GS} = 10V,$ $I_{D} = 14A, R_{G} = 6\Omega$	
Turn-On Rise Time	t _R	-	12	_	20		
Turn-Off Delay Time	tD(OFF)	_	37	_	ns		
Turn-Off Fall Time	tF	-	21	_			
Body Diode Reverse Recovery Time	trr		42	_	ns	1- 110 di/dt 1000/us	
Body Diode Reverse Recovery Charge	Q _{RR}	_	53	_	nC	I _S = 14A, di/dt = 100A/μs	

Notes:

- 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
 7. Thermal resistance from junction to soldering point (on the exposed drain pad).
- 8. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25$ °C.
- 9. Short duration pulse test used to minimize self-heating effect.
- 10. Guaranteed by design. Not subject to product testing.







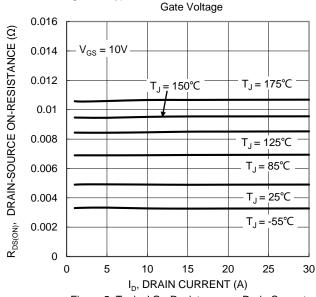
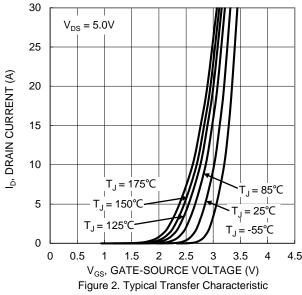
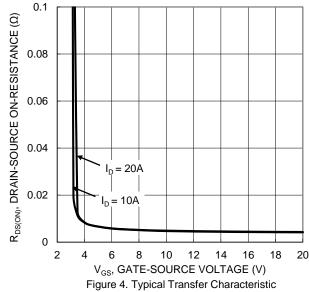
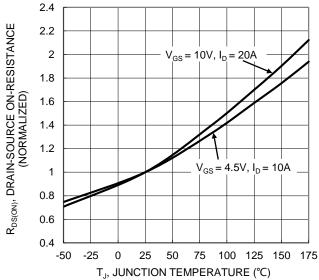


Figure 5. Typical On-Resistance vs. Drain Current and Temperature











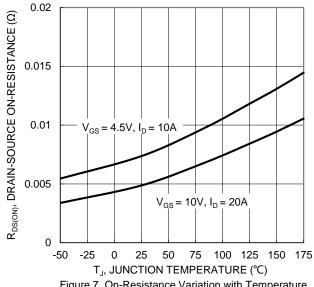
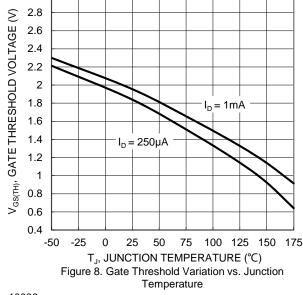


Figure 7. On-Resistance Variation with Temperature



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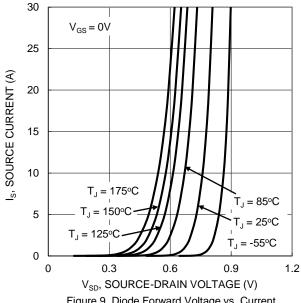
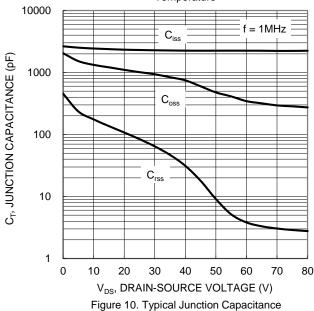
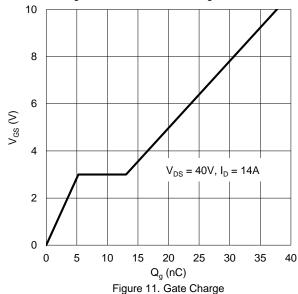


Figure 9. Diode Forward Voltage vs. Current





1000 R_{DS(ON)} 100 ID, DRAIN CURRENT (A) 10 $T_{J(Max)} = 175$ °C $P_W = 1ms$ Single Pulse = 10 msDUT on Infinite Heatsink $V_{GS} = 10V$ 0.1 0.1 10 100 V_{DS}, DRAIN-SOURCE VOLTAGE (V)



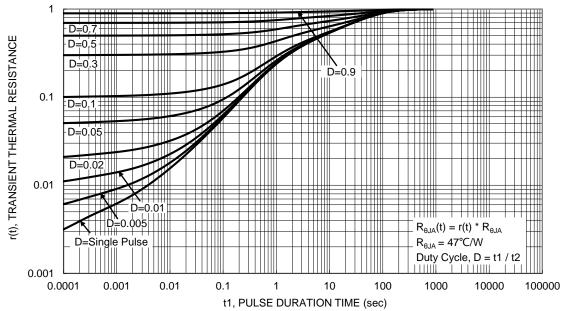


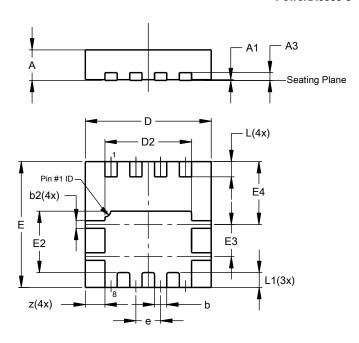
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8

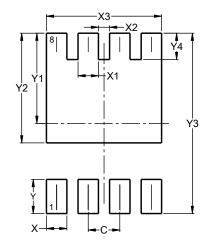


PowerDI3333-8					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05	0.02		
A3	_	_	0.203		
b	0.27	0.37	0.32		
b2	0.15	0.25	0.20		
D	3.25	3.35	3.30		
D2	2.22	2.32	2.27		
Е	3.25	3.35	3.30		
E2	1.56	1.66	1.61		
E3	0.79	0.89	0.84		
E4	1.60	1.70	1.65		
е	_	_	0.65		
L	0.35	0.45	0.40		
L1	_	_	0.39		
Z	_	_	0.515		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8



Dimensions	Value (in mm)		
С	0.650		
X	0.420		
X1	0.420		
X2	0.230		
Х3	2.370		
Y	0.700		
Y1	1.850		
Y2	2.250		
Y3	3.700		
Y4	0.540		



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